

BC807,215 Datasheet



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DiGi Electronics Part Number BC807,215-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number BC807,215

Description TRANS PNP 45V 0.5A TO236AB

Detailed Description Bipolar (BJT) Transistor PNP 45 V 500 mA 80MHz 25

0 mW Surface Mount TO-236AB



Tel: +00 852-30501935

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BC807,215	Nexperia USA Inc.
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
PNP	500 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
45 V	700mV @ 50mA, 500mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
100nA (ICBO)	100 @ 100mA, 1V
Power - Max:	Frequency - Transition:
250 mW	80MHz
Operating Temperature:	Grade:
150°C (TJ)	Automotive
Qualification:	Mounting Type:
AEC-Q101	Surface Mount
Package / Case:	Supplier Device Package:
TO-236-3, SC-59, SOT-23-3	TO-236AB
Base Product Number:	
BC807	

Environmental & Export classification

8541.21.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



BC807 series

45 V, 500 mA PNP general-purpose transistors

Rev. 8 — 1 July 2022

Product data sheet

1. General description

PNP general-purpose transistor in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	Package	NPN complement		
	Nexperia	JEDEC	JEITA	
BC807	SOT23	TO-236AB	-	BC817
BC807-16				BC817-16
BC807-25				BC817-25
BC807-40				BC817-40

2. Features and benefits

- High current
- · Three current gain selections

3. Applications

· General-purpose switching and amplification

4. Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base; T _{amb} = 25 °C		-	-	-45	V
I _C	collector current	T _{amb} = 25 °C		-	-	-500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C		-	-	-1	Α
h _{FE}	DC current gain	·			•		
	BC807	V_{CE} = -1 V; I_{C} = -100 mA T_{amb} = 25 °C	[1]	100	-	600	
	BC807-16		[1]	100	-	250	
	BC807-25		[1]	160	-	400	
	BC807-40		[1]	250	-	600	

[1] pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02$



Nexperia

45 V, 500 mA PNP general-purpose transistors

BC807 series

5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	<u></u> 3	C
2	E	emitter		B—
3	С	collector		, h
				E sym132
			1	

6. Ordering information

Table 4. Ordering information

Type number	Package	Package				
	Name	Description	Version			
BC807	TO-236AB	Plastic surface-mounted package; 3 leads	SOT23			
BC807-16						
BC807-25						
BC807-40						

7. Marking

Table 5. Marking

Type number	Marking code[1]
BC807	5D%
BC807-16	5A%
BC807-25	5B%
BC807-40	5C%

[1] % = placeholder for manufacturing site code

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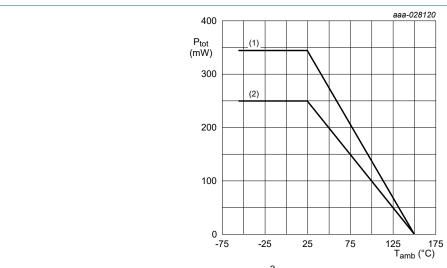
8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter; T _{amb} = 25 °C	open emitter; T _{amb} = 25 °C		-50	V
V_{CEO}	collector-emitter voltage	open base; T _{amb} = 25 °C		-	-45	V
V _{EBO}	emitter-base voltage	open collector; T _{amb} = 25 °C		-	-5	V
I _C	collector current	T _{amb} = 25 °C		-	-500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C		-1	Α
I _{BM}	peak base current	single pulse; $t_p \le 1$ ms; $T_{amb} = 25$ °C	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C		-200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1] [2]	-	250	mW
			[3] [2]	-	345	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature				150	°C
T _{stg}	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Valid for all available selection groups.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm².



- (1) FFR4 PCB, single-sided copper; 1 ${\rm cm}^2$
- (2) FR4 PCB, single-sided copper; standard footprint

Fig. 1. Power derating curves for SOT23

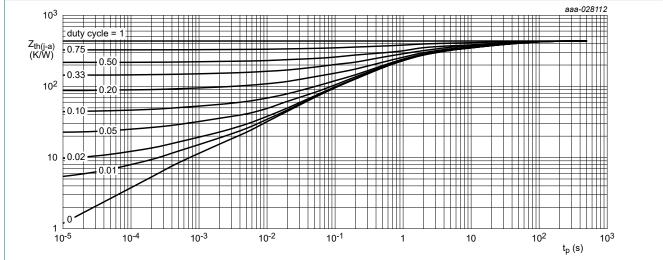
45 V, 500 mA PNP general-purpose transistors

9. Thermal characteristics

Table 7. Thermal characteristics

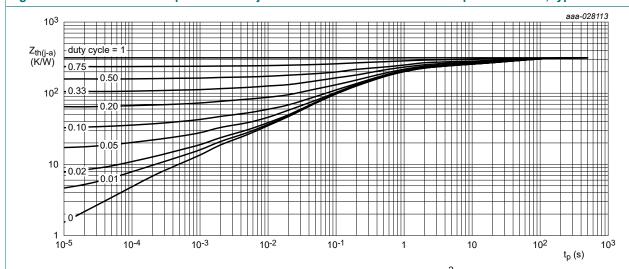
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	500	K/W
			[3] [2]	-	-	362	K/W

- [1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.
- [2] Valid for all available selection groups.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; monting pad for collector 1 cm².



FR4 PCB, single-sided, tin-plated and standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm².

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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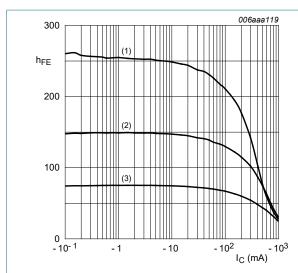
10. Characteristics

Table 8. Characteristics

				Тур	Max	Unit
collector-base breakdown voltage	$I_C = -100 \ \mu\text{A}; \ I_E = 0 \ \text{A}; \ T_{amb} = 25 \ ^{\circ}\text{C}$		-50	-	-	V
collector-emitter breakdown voltage	I _C = -10 mA; I _E = 0 A; T _{amb} = 25 °C		-45	-	-	V
emitter-base breakdown voltage	$I_E = -100 \ \mu A; \ I_C = 0 \ A; \ T_{amb} = 25 \ ^{\circ}C$		-5	-	-	V
collector-base	V _{CB} = -20 V; I _E = 0 A; T _{amb} = 25 °C		-	-	-100	nA
cut-off current	V _{CB} = -20 V; I _E = 0 A; T _j = 150 °C		-	-	-5	μΑ
emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	-100	nA
DC current gain			'		'	_
BC807	V _{CE} = -1 V; I _C = -100 mA; T _{amb} = 25 °C	[1]	100	-	600	
BC807-16		[1]	100	-	250	
BC807-25		[1]	160	-	400	
BC807-40		[1]	250	-	600	
DC current gain	V _{CE} = -1 V; I _C = -500 mA; T _{amb} = 25 °C	[1]	40	-	-	
collector-emitter saturation voltage	$I_C = -500 \text{ mA}; I_B = -50 \text{ mA}; T_{amb} = 25 \text{ °C}$	[1]	-	-	-700	mV
base-emitter voltage	V _{CE} = -1 V; I _C = -500 mA; T _{amb} = 25 °C		-	-	-1.2	V
transition frequency	V _{CE} = -5 V; I _C = -10 mA; f = 100 MHz; T _{amb} = 25 °C		80	-	-	MHz
collector capacitance	V_{CB} = -10 V; I_{E} = i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	5	-	pF
	collector-emitter breakdown voltage emitter-base breakdown voltage collector-base cut-off current emitter-base cut-off current DC current gain BC807 BC807-16 BC807-25 BC807-40 DC current gain collector-emitter saturation voltage base-emitter voltage	collector-emitter breakdown voltage	collector-emitter breakdown voltage	collector-emitter breakdown voltage $I_C = -10 \text{ mA}$; $I_E = 0 \text{ A}$; $T_{amb} = 25 ^{\circ}\text{C}$ -45 emitter-base breakdown voltage $I_E = -100 \mu\text{A}$; $I_C = 0 \text{A}$; $T_{amb} = 25 ^{\circ}\text{C}$ -5 collector-base cut-off current $V_{CB} = -20 \text{V}$; $I_E = 0 \text{A}$; $T_{amb} = 25 ^{\circ}\text{C}$ - emitter-base cut-off current $V_{CB} = -20 \text{V}$; $I_C = 0 \text{A}$; $V_{CB} = 0 \text{A}$; V	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c} \text{collector-emitter} \\ \text{breakdown voltage} \\ \end{array} \begin{array}{c} I_{\text{C}} = -10 \text{ mA; } I_{\text{E}} = 0 \text{ A; } T_{\text{amb}} = 25 \text{ °C} \\ \end{array} \begin{array}{c} -45 \\ -5 \\ -5 \\ -5 \\ \end{array} \begin{array}{c} -6 \\ -5 \\ -5 \\ -5 \\ -5 \\ -5 \\ -5 \\ -5 \\$

 $[\]begin{array}{ll} [1] & \text{pulsed; } t_p \leq 300 \; \mu \text{s; } \delta \leq 0.02 \\ [2] & V_{BE} \; \text{decreases by about 2 mV/K with increasing temperature.} \end{array}$

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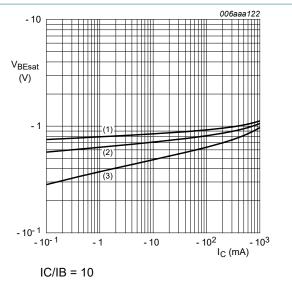
$$V_{CE} = -1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 4. BC807-16: DC current gain as a function of collector current; typical values

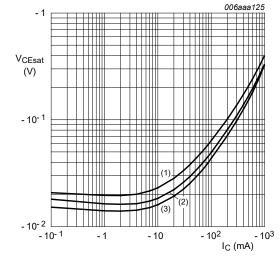


(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 5. BC807-16: Base-emitter saturation voltage as a function of collector current; typical values

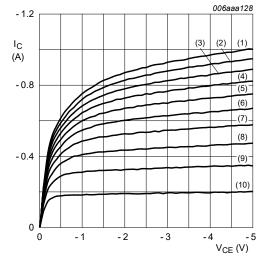


IC/IB = 10

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55$$
 °C

Fig. 6. BC807-16: Collector-emitter saturation voltage as a function of collector current; typical values



T_{amb} = 25 °C

(1) $I_B = -16.0 \text{ mA}$

(2) $I_B = -14.4 \text{ mA}$

(3) $I_B = -12.8 \text{ mA}$

(4) $I_B = -11.2 \text{ mA}$

 $(5) I_B = -9.6 \text{ mA}$

(6) $I_B = -8.0 \text{ mA}$

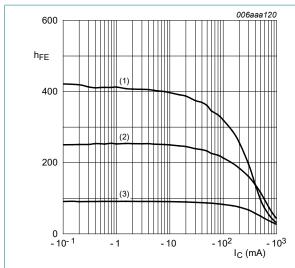
 $(7) I_B = -6.4 \text{ mA}$

(8) $I_B = -4.8 \text{ mA}$ (9) $I_B = -3.2 \text{ mA}$

 $(10) I_B = -1.6 \text{ mA}$

Fig. 7. BC807-16: Collector current as a function of collector-emitter voltage; typical values

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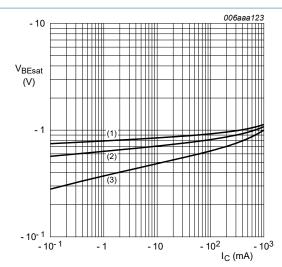
$$V_{CE} = -1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 8. BC807-25: DC current gain as a function of collector current; typical values

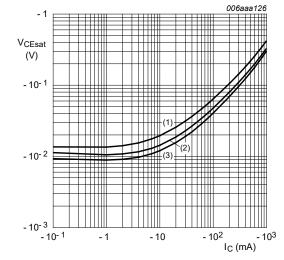


(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 9. BC807-25: Base-emitter saturation voltage as a function of collector current; typical values

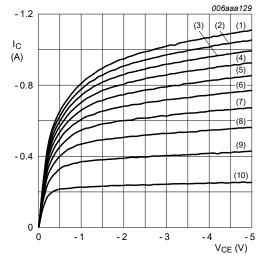


$$IC/IB = 10$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55$$
 °C

Fig. 10. BC807-25: Collector-emitter saturation voltage as a function of collector current; typical values



$$T_{amb} = 25 \, ^{\circ}C$$

(1)
$$I_B = -13.0 \text{ mA}$$

(2)
$$I_B = -11.7 \text{ mA}$$

(3)
$$I_B = -10.4 \text{ mA}$$

$$(4) I_B = -9.1 \text{ mA}$$

$$(5) I_B = -7.8 \text{ mA}$$

(6)
$$I_B = -6.5 \text{ mA}$$

$$(7) I_B = -5.2 \text{ mA}$$

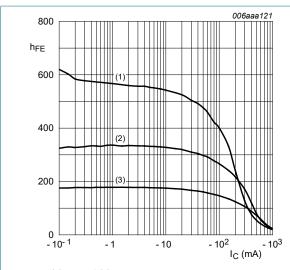
(8)
$$I_B = -3.9 \text{ mA}$$

(9)
$$I_B = -2.6 \text{ mA}$$

$$(10) I_B = -1.3 \text{ mA}$$

Fig. 11. BC807-25: Collector current as a function of collector-emitter voltage; typical values

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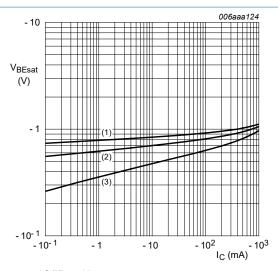
$$V_{CE} = -1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Fig. 12. BC807-40: DC current gain as a function of collector current; typical values

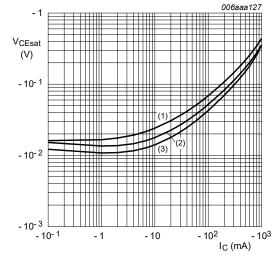


(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 13. BC807-40: Base-emitter saturation voltage as a function of collector current; typical values

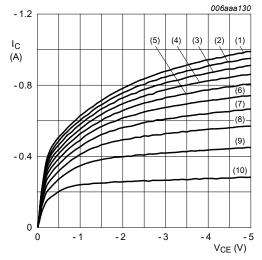


$$IC/IB = 10$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55$$
 °C

Fig. 14. BC807-40: Collector-emitter saturation voltage as a function of collector current; typical values



$$T_{amb} = 25 \, ^{\circ}C$$

(1)
$$I_B = -12.0 \text{ mA}$$

$$(2) I_B = -10.8 \text{ mA}$$

$$(3) I_B = -9.6 \text{ mA}$$

$$(4) I_B = -8.4 \text{ mA}$$

(5)
$$I_B = -7.2 \text{ mA}$$

(6)
$$I_B = -6.0 \text{ mA}$$

$$(7) I_B = -4.8 \text{ mA}$$

(8)
$$I_B = -3.6 \text{ mA}$$

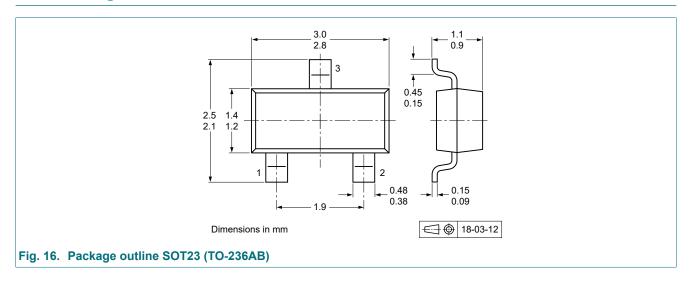
(9)
$$I_B = -2.4 \text{ mA}$$

$$(10) I_B = -1.2 mA$$

Fig. 15. BC807-40: Collector current as a function of collector-emitter voltage; typical values

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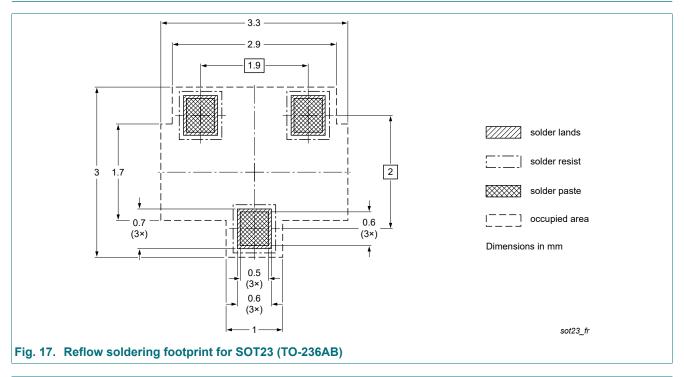
11. Package outline

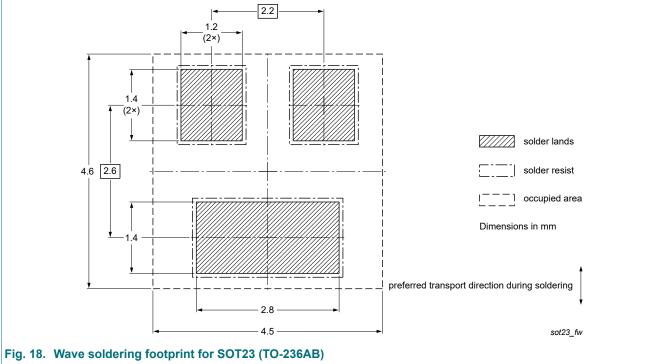


9 / 13

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12. Soldering





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13. Revision history

Table 9. Revision history

Table 9. Revision history	I	I		_		
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
BC807_SER v.8	20220701	Product data sheet	-	BC807_SER v.7		
Modifications:	 Product(s) changed to non-automotive qualification. Please refer to nexperia.com for automotive (-Q) product alternative(s). 					
BC807_SER v.7	20180615	Product data sheet	-	BC807_BC807W_BC327 v.6		
BC807_BC807W_BC327 v.6	20091117	Product data sheet	-	BC807_BC807W_BC327 v.5		
BC807_BC807W_BC327 v.5	20050221	Product data sheet	CPCN200302007F CPCN200405006F	BC807 v.4 BC807W v.3 BC327 v.3		
BC807 v.4	20040116	Product Specification	-	BC807 v.3		
BC807W v.3	19990518	Product Specification	-	BC807W_808W_CNV v.2		
BC327 v.3	19990415	Product Specification	-	BC327 v.2		

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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Tel: +00 852-30501935